



# MEG II 実験における 背景事象抑制に向けた超低物質 RPCの読み出しに関する研究

講演番号 19aG22-2

(講演番号 19aG22-1 との連続講演)

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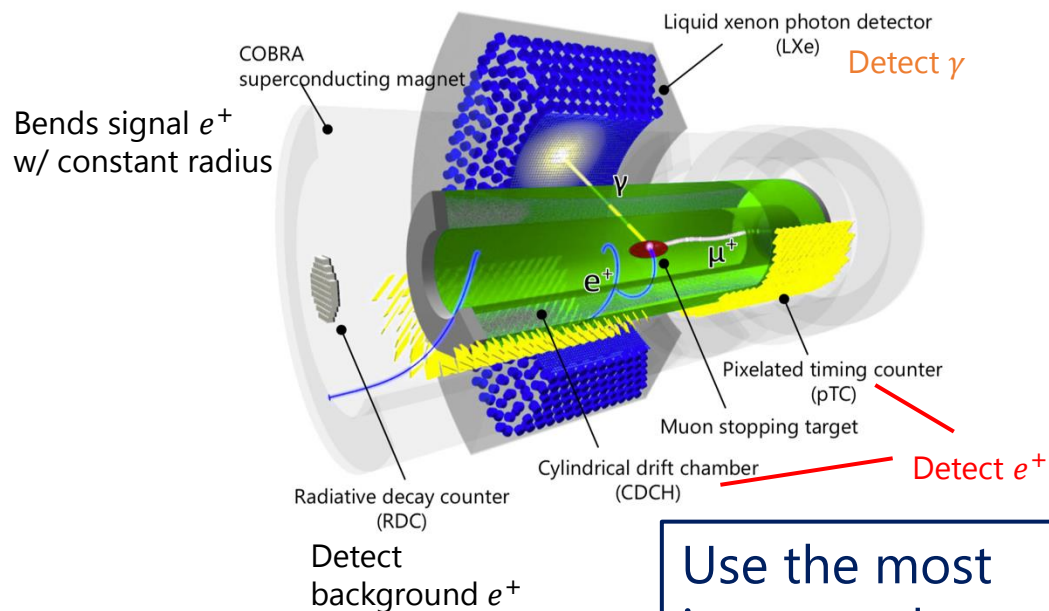
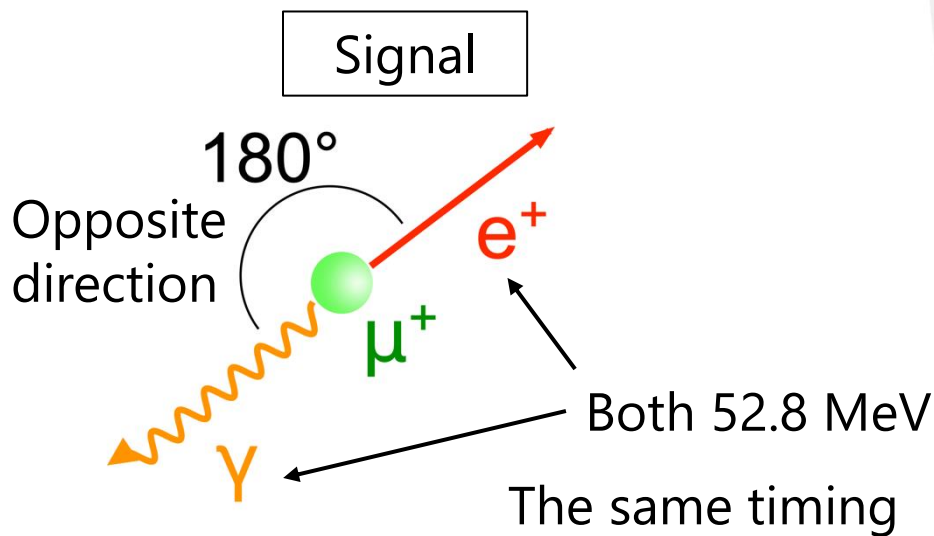
日本物理学会第75回年次大会 (2020年)

# Outline

- Introduction
  - MEG II
  - RPC
  - Pileup inefficiency
  - Prototype RPC readout
  - Suppress ringing tail
- Lab test
- Summary & prospects

# MEG II signal

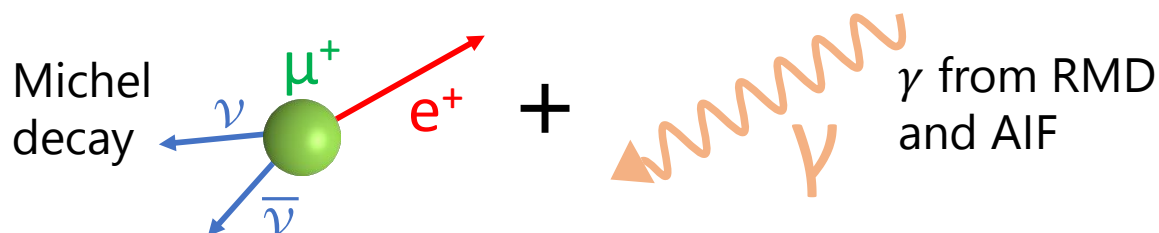
- MEG II searches for charged lepton flavour violating decay:  $\mu^+ \rightarrow e^+ \gamma$
- MEG II signal is identified by the kinematics



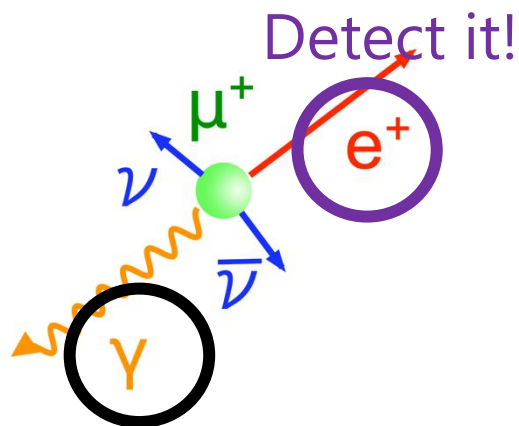
Use the most intense  $\mu$  beam:  
DC and beam rate  
 $\sim 7 \times 10^7$  /s

# MEG II background

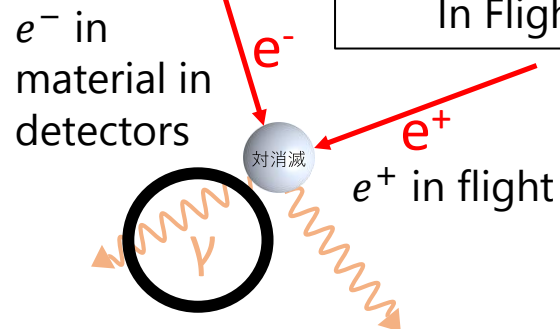
Dominant background = Accidental BG  
= Coincidence of  $e^+$  from Michel decay and  $\gamma$  from RMD or AIF



RMD: Radiative Muon Decay



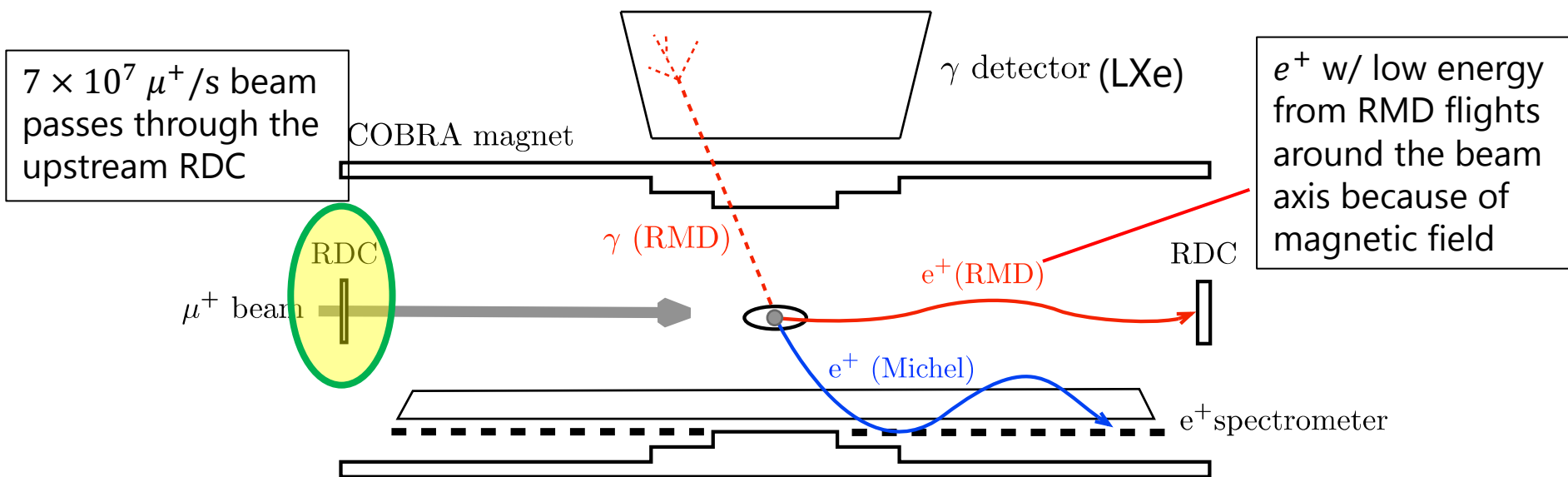
AIF: Annihilation In Flight



Detect  $e^+$  with low energy (1-5 MeV) from RMD to identify  $\gamma$  from RMD

# BG identification detectors

- Radiative decay counters (RDCs) are installed in both upstream and downstream to detect  $e^+$  from RMD



The upstream RDC has strict requirements because it has to be passed through by  $7 \times 10^7 \mu^+ / s$  beam and to detect  $e^+$  from RMD

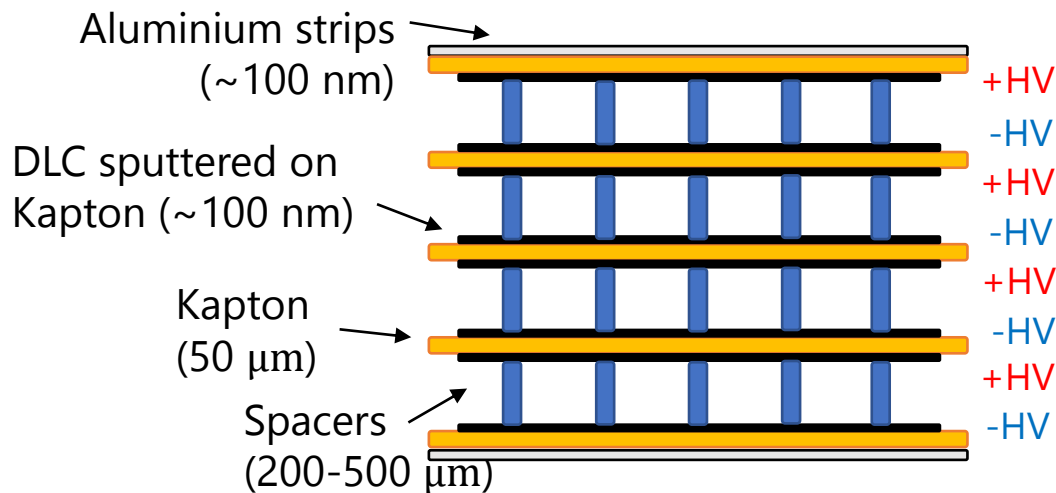
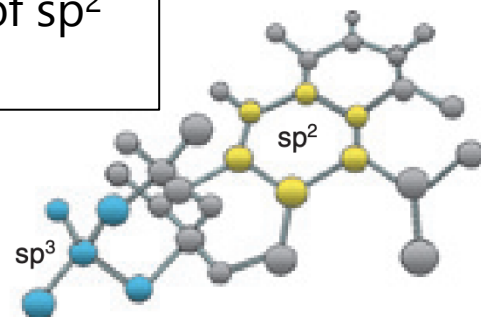
# Upstream RDC requirements

1. Material budget:  $< 0.1\% X_0$   
( $\leftarrow \mu^+$  beam passes through the detector)
  2. 90% efficiency for  $e^+$  with 1-5 MeV
  3. 1 ns time resolution  
( $\leftarrow$  RMD identification with time difference b/w  $e^+$  &  $\gamma$ )
  4. Rate capability & radiation hardness  
( $\leftarrow 7 \times 10^7 \mu^+ /s$  with 21 MeV/c &  $> 60$  weeks run)
  5. Detector size: 20-cm diameter  
( $\leftarrow 45\%$  acceptance in the one RDC, 90% in total incl. downstream)
- Candidate for the upstream RDC is **ultra-low material resistive plate chamber (RPC)**

# Proposed RPC design for MEG II

- Gas: R134a (Freon) based
- DLC is used as resistive electrodes
- Achieve ultra low-material budget
- Aluminised Kapton readout strips are
  - at both anode and cathode
  - orthogonal to each other
- Readout region is segmented

Diamond like carbon (DLC) has mixed structure of  $sp^2$  bond and  $sp^3$  bond



# Pileup of $\mu^+$ beam & RMD $e^+$

## Requirements for RPC

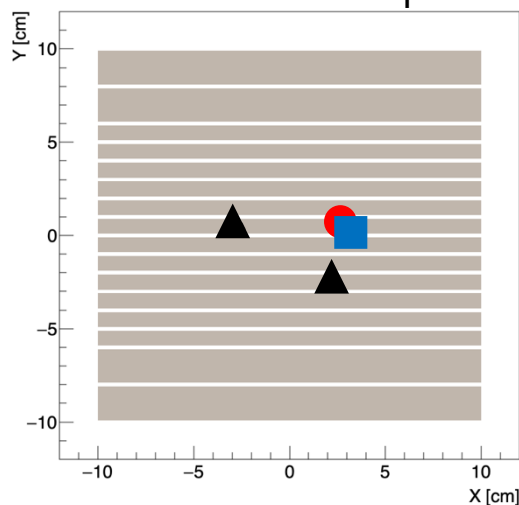
- 90% efficiency for 1-5 MeV  $e^+$
- Rate capability  
( $10^8 \mu/s$  with 21 MeV/c)



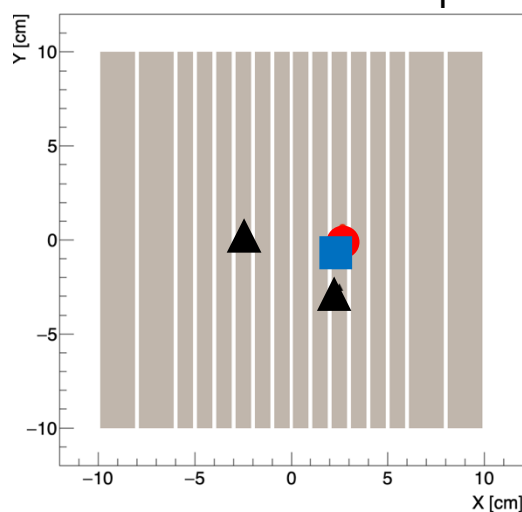
Pileup of high-rate  $\mu^+$  beam and RMD  $e^+$  causes inefficiency for RMD  $e^+$



Anode readout strips



Cathode readout strips



- The segmented design can reduce pileup
- Calculate probability of the pileup
  - ● & ■ at the same region at the same timing
  - ● & ▲ in the same strip at the same timing

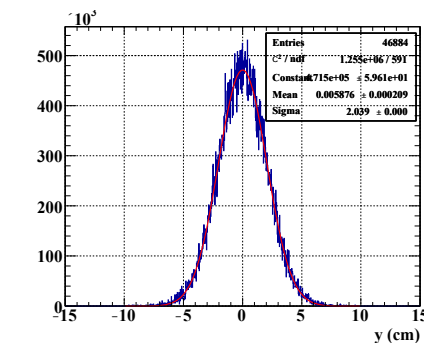
●: RMD  $e^+$    ■:  $\mu^+$  at the same position as RMD  $e^+$   
▲:  $\mu^+$  in the same strip as RMD  $e^+$



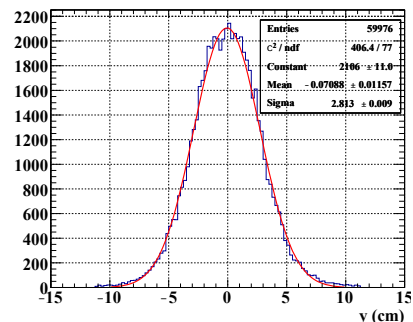
# Pileup of $\mu^+$ beam & RMD $e^+$

- Calculate pileup probability  $p_i$  per readout segmented region as a function of signal duration
- Calculate total pileup inefficiency  $P$  from  $p_i$

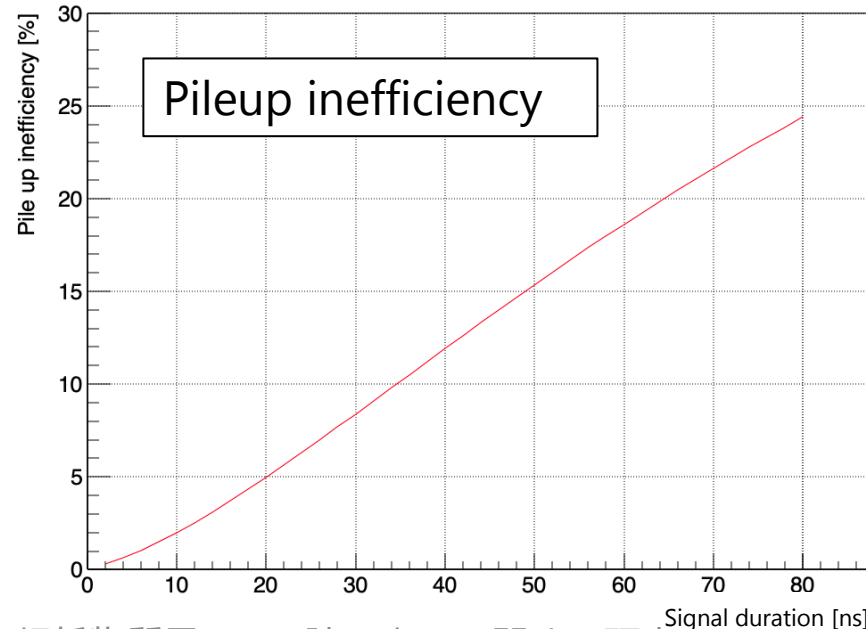
• Inefficiency due to pileup is small enough ( $< 2.0\%$ ) if signal duration within 10 ns



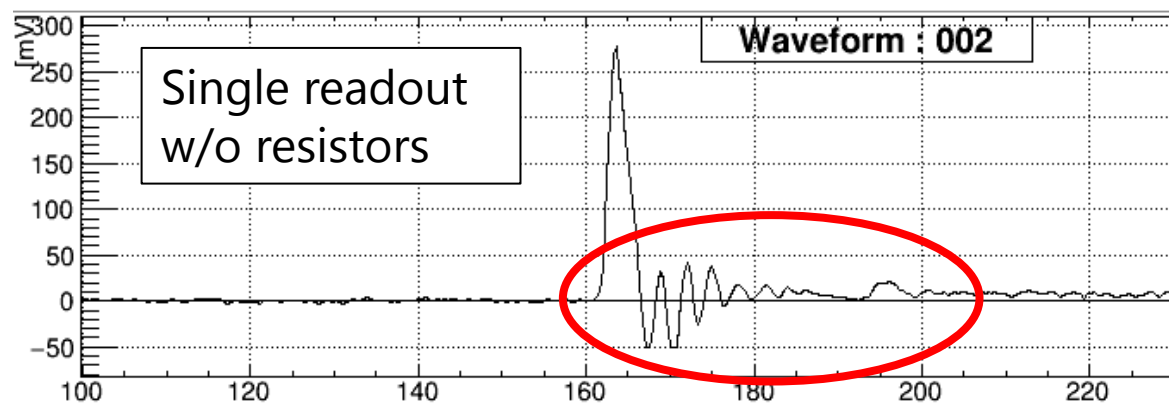
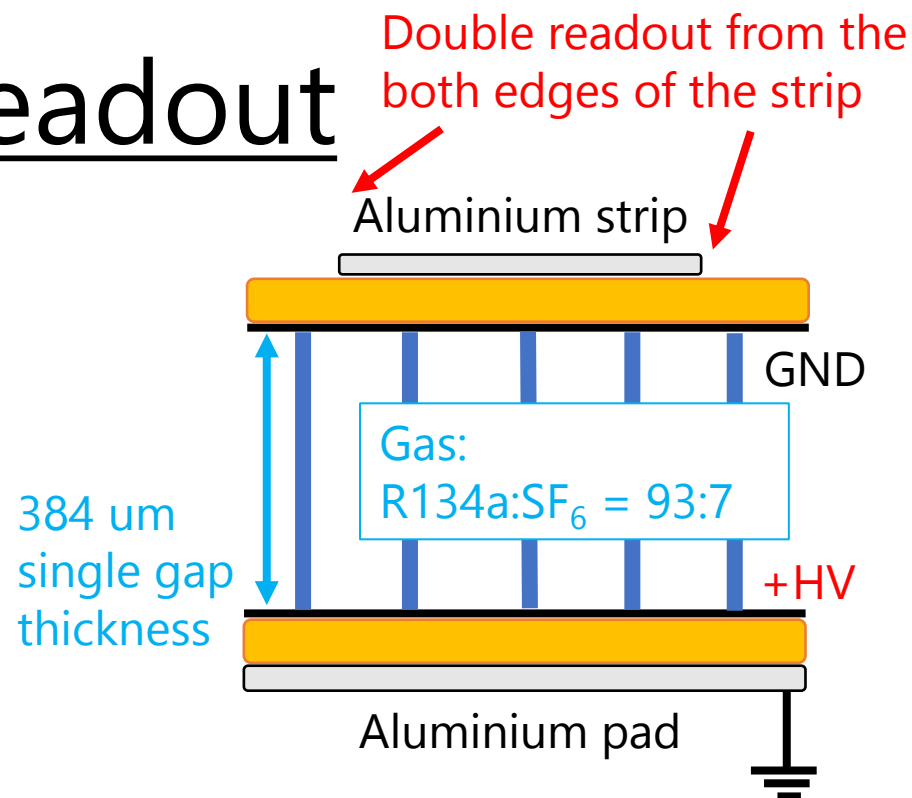
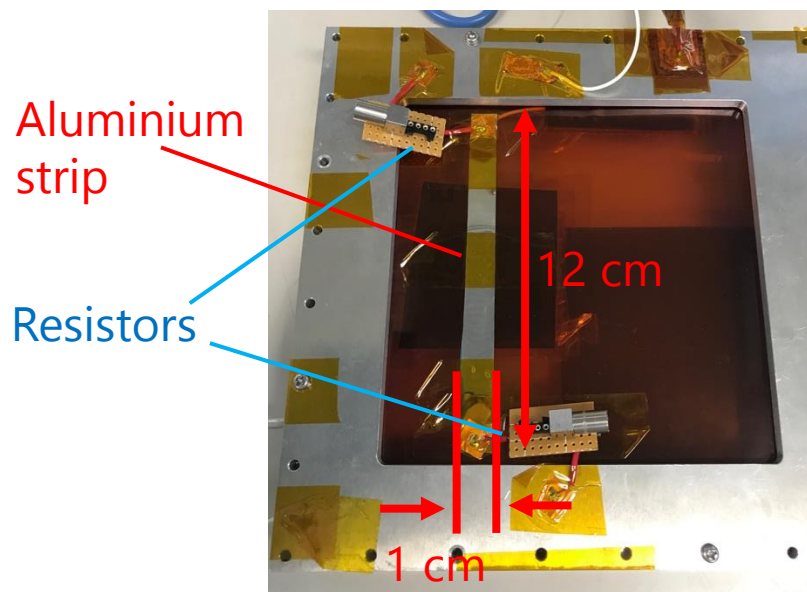
$\mu^+$  beam divergence  
 $\sigma = 2.0$  cm



RMD  $e^+$  divergence  
 $\sigma = 2.8$  cm



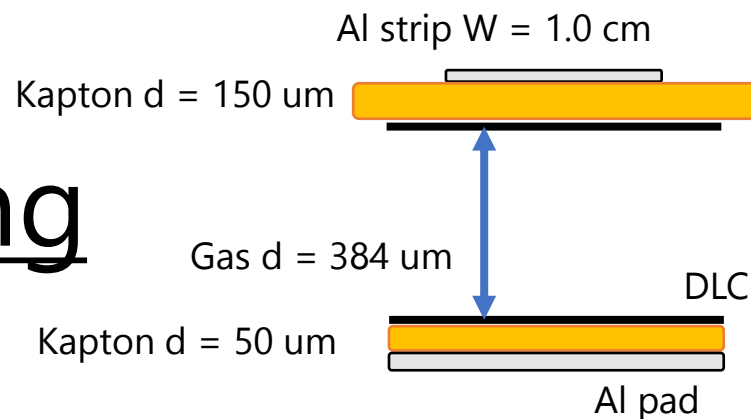
# Prototype RPC readout



Ringing tail was observed because of

- reflection due to impedance mismatching?
- resonance due to stray RLC structure?

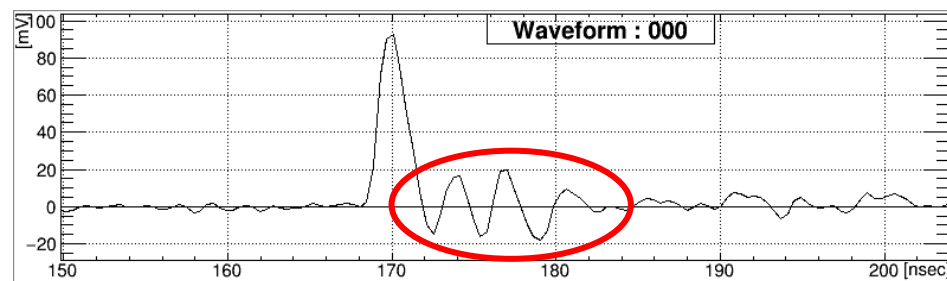
# Suppress the ringing



- Characteristic impedance of the aluminium strip is estimated at  $13.2 \Omega$
- Co-axial cable with characteristic impedance of  $50 \Omega$  will be used for signal transmission b/w the strip and readout electronics
- Possible solutions:
  - Improve impedance matching at preamplifier
  - ← Not easy to place preamplifier near RPC due to limited space
  - Insert resistors to damp the ringing



Suppress the ringing as much as possible w/o preamplifier



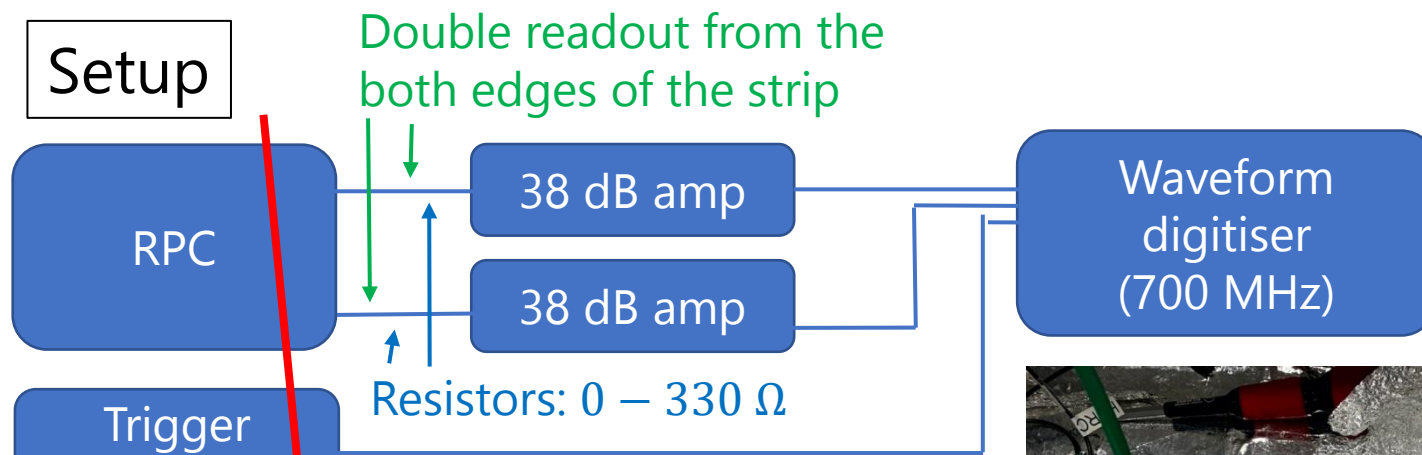
→ Insert resistors b/w the strip & co-axial cable to damp it

# Outline

- Introduction
- Lab test
  - Setup and purposes
  - Effect of resistors on ringing
  - Effect of resistors on RPC performance
- Summary & prospects

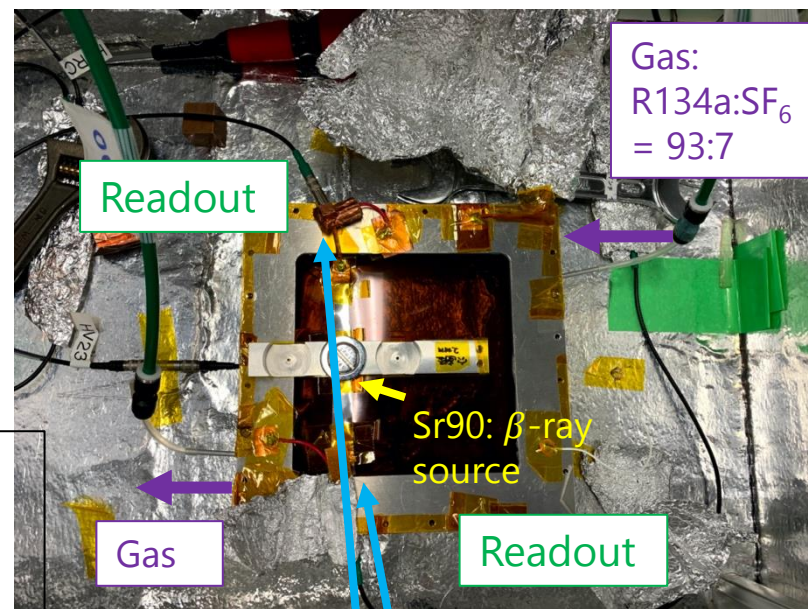
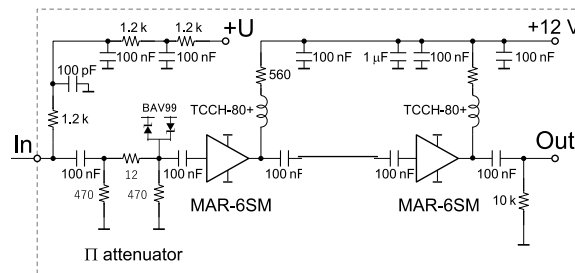
# Lab test on effect of resistors

## Setup



Collimated  $\beta$ -ray

38 dB amplifier



Gas:  
R134a:SF<sub>6</sub>  
= 93:7

## Purposes:

- Examine how much resistors suppress ringing
- Examine how much resistors deteriorate RPC performance

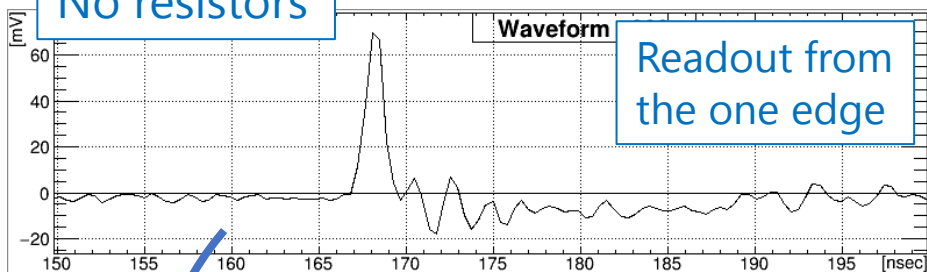
Resistors

# Waveform

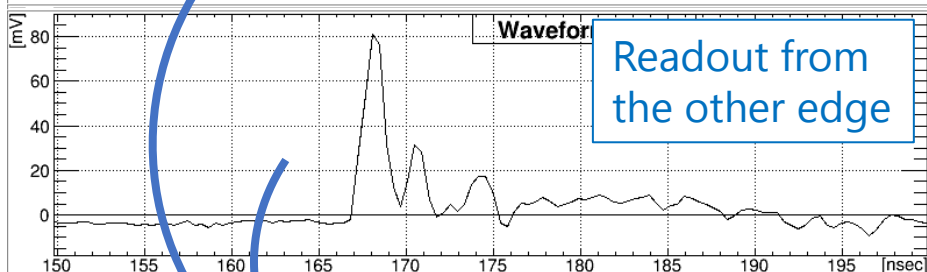
## Inserted resistors

- change ringing tail
- suppress ringing only in summed waveform

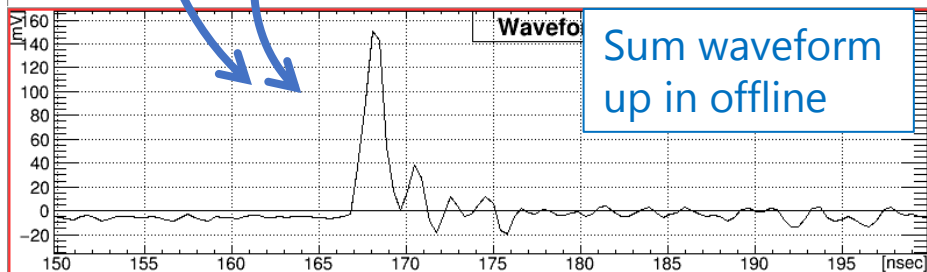
No resistors



Readout from the one edge

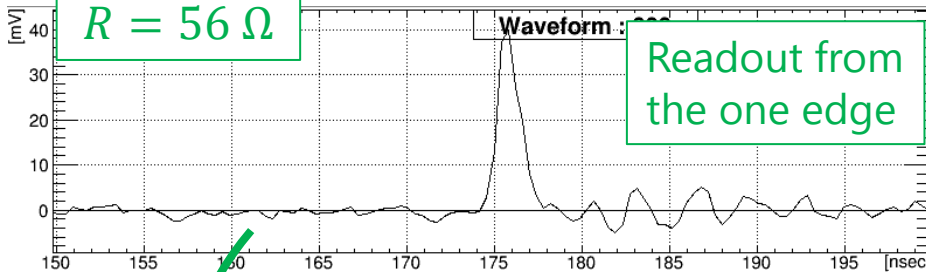


Readout from the other edge

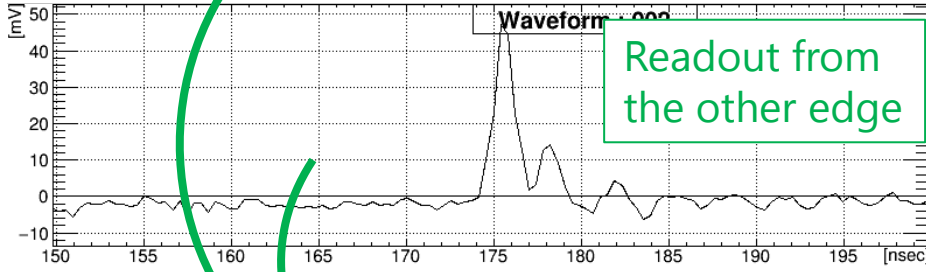


Sum waveform up in offline

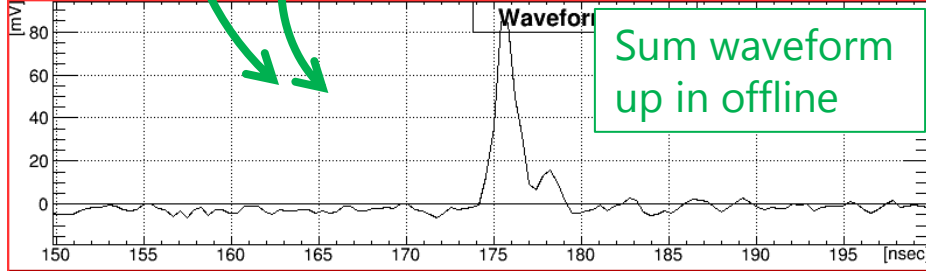
$R = 56 \Omega$



Readout from the one edge



Readout from the other edge



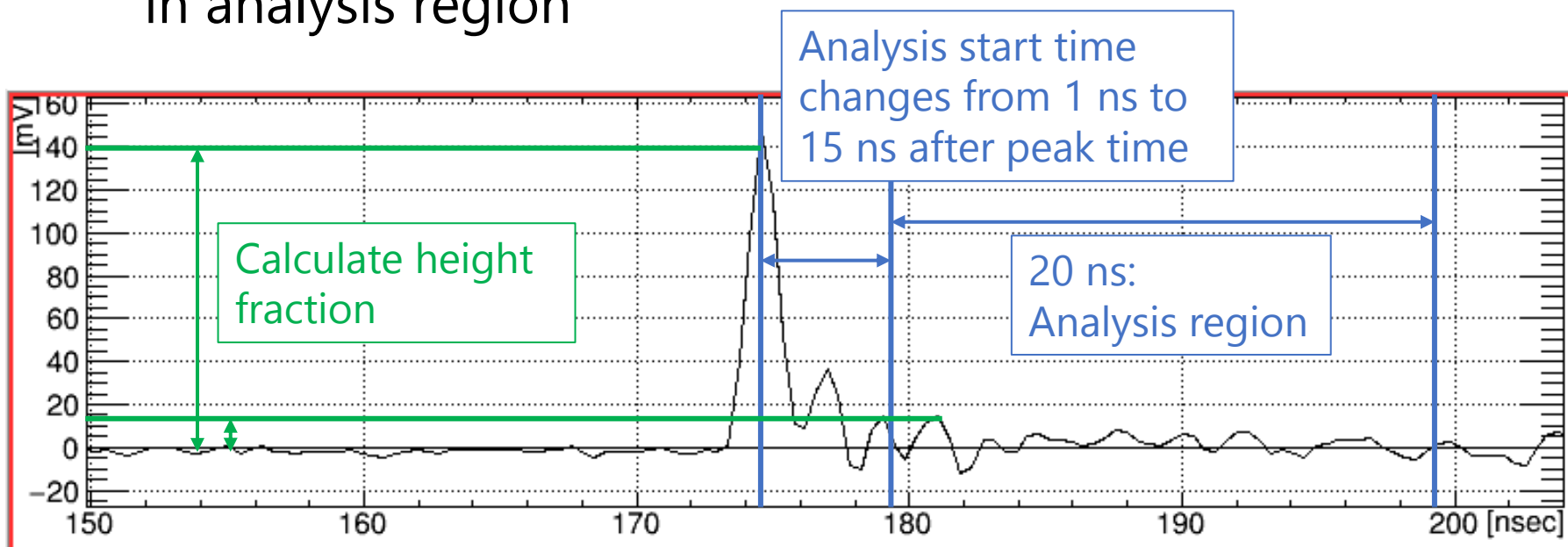
Sum waveform up in offline

- How fast was ringing suppressed?
- How much was ringing suppressed?

Next slide

# Analyze height after peak

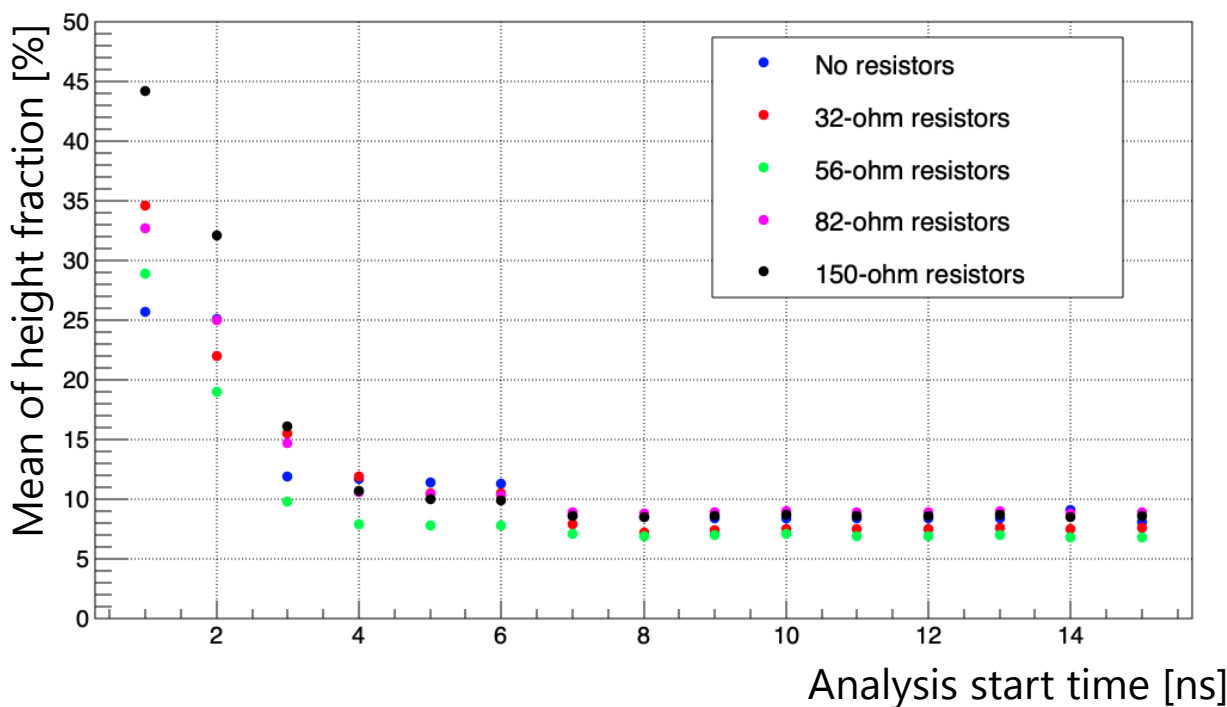
- Investigate how fast and how much ringing was suppressed
- "Analysis start time" is defined as start time of 20-ns analysis region
- Calculate the ratio of signal height to maximum height in analysis region



# Height fraction

- 56  $\Omega$  resistors suppressed ringing little faster than the others
- However, this improvement is not enough

Height fraction vs Time after peak time





# Height distribution

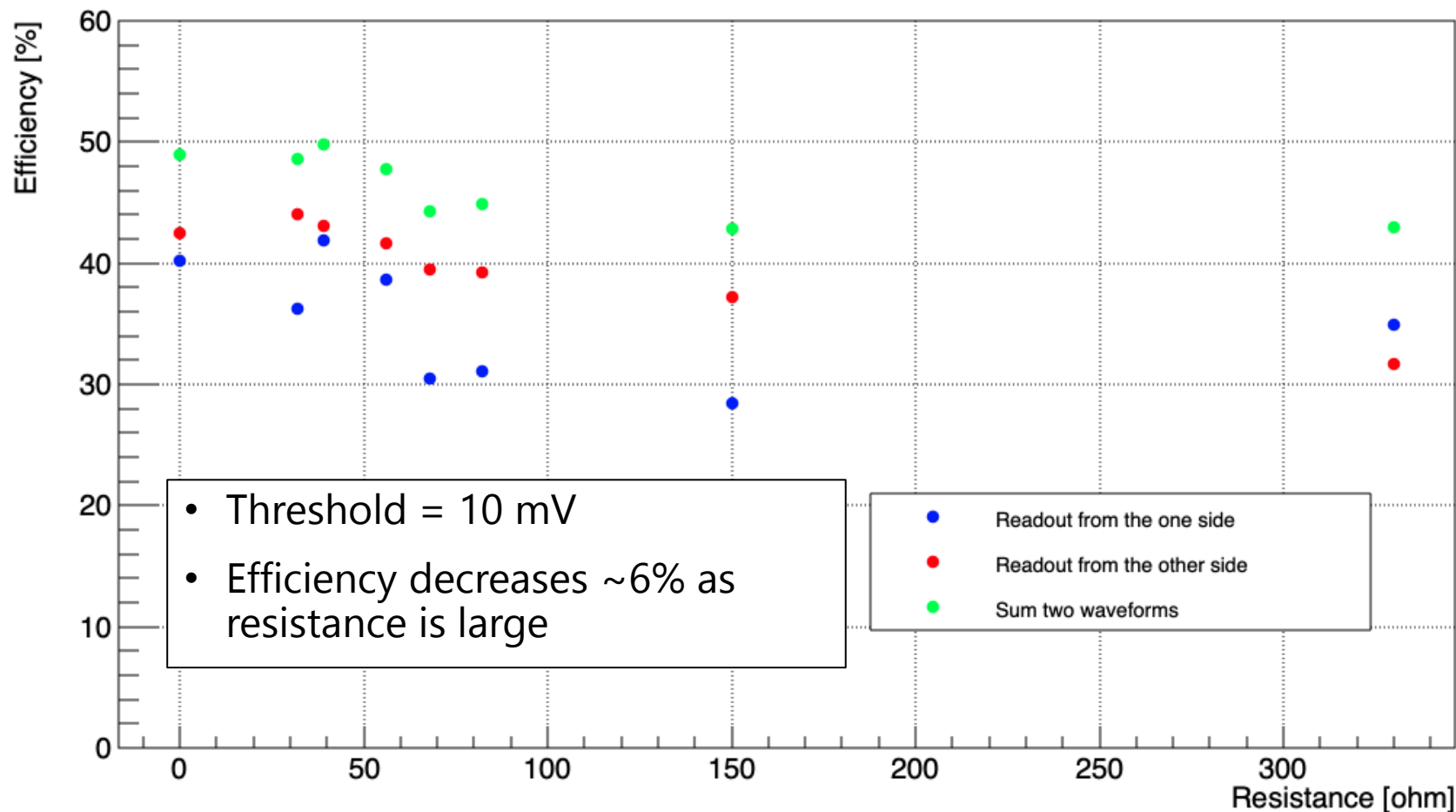


# Efficiency

Achieve 40% single layer efficiency w/ any resistance

→ 90% four-layer efficiency can be achieved even if inserting resistors according to  $\epsilon_n = 1 - (1 - \epsilon_1)^n$

Efficiency vs Resistance



# Outline

- Introduction
- Lab test
- Summary & prospects

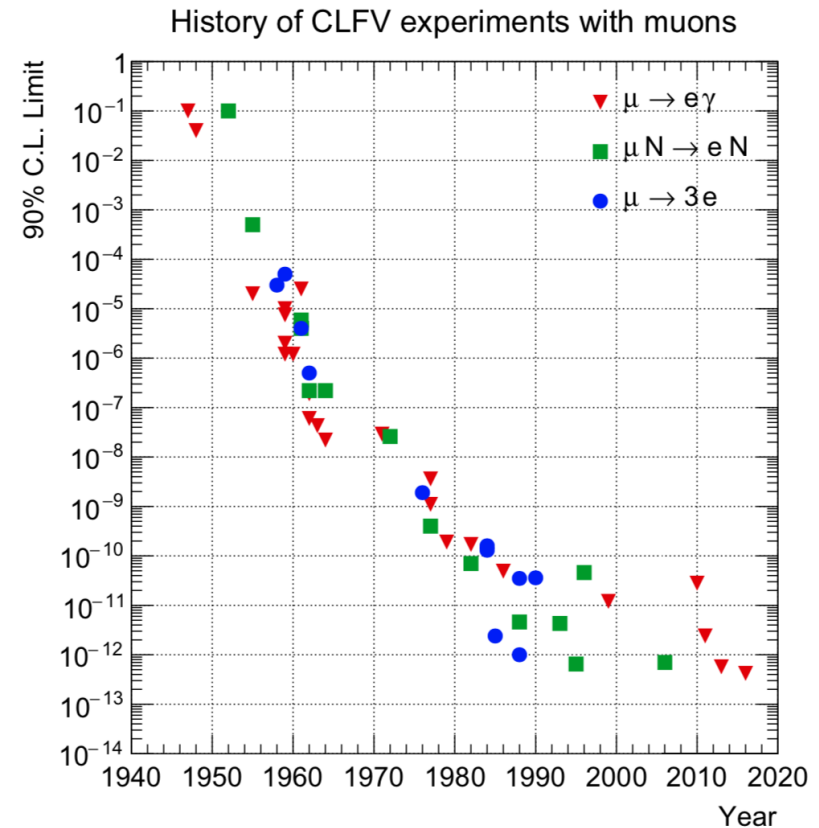
# Summary & prospects

- Summary
  - Readout w/o resistors generated ringing
  - Resistors inserted b/w Al readout strip & LEMO cable change waveform and suppress ringing in summed waveform
  - They also made signal height smaller
- Prospects
  - Explain waveform theoretically or by simulation
  - Optimise readout and resistance

# Backups

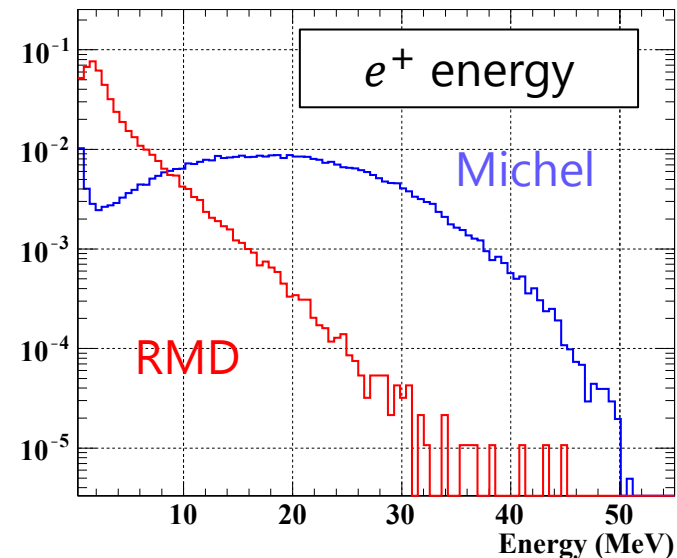
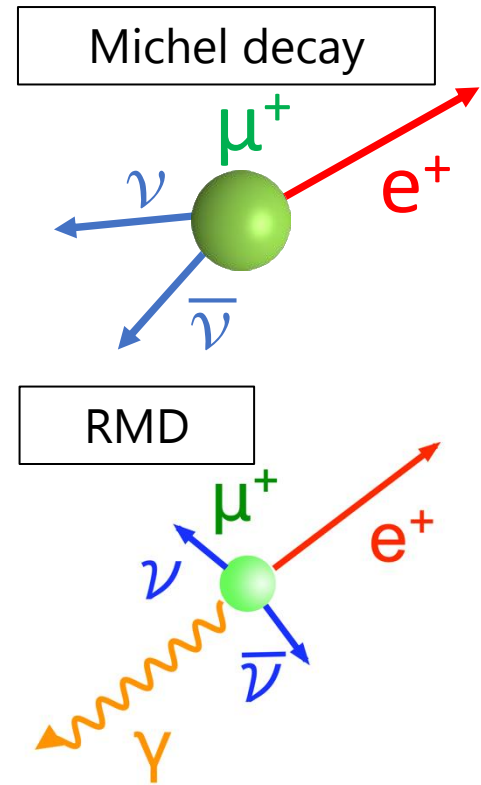
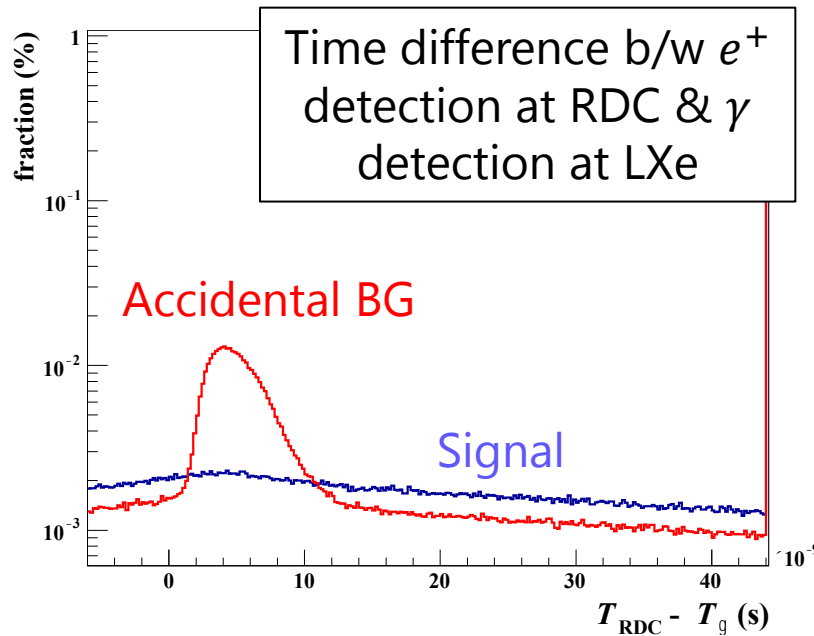
# Physics of $\mu^+ \rightarrow e^+ \gamma$

- Charged lepton flavour violation (cLFV) is forbidden in the standard model (SM)
  - In the SM,  $\mathcal{B}(\mu \rightarrow e \gamma) < 10^{-50}$
- Some physics models beyond the SM (SUSY-GUT, SUSY-seesaw) say  $\mathcal{B}(\mu \rightarrow e \gamma)$  is  $10^{-11}$  –  $10^{-14}$
- MEG experiment gave the upper limit of  $\mu \rightarrow e \gamma$   $5.3 \times 10^{-13}$  for the branching ratio
- $\mu \rightarrow e \gamma$  observation strengthen makes models beyond SM



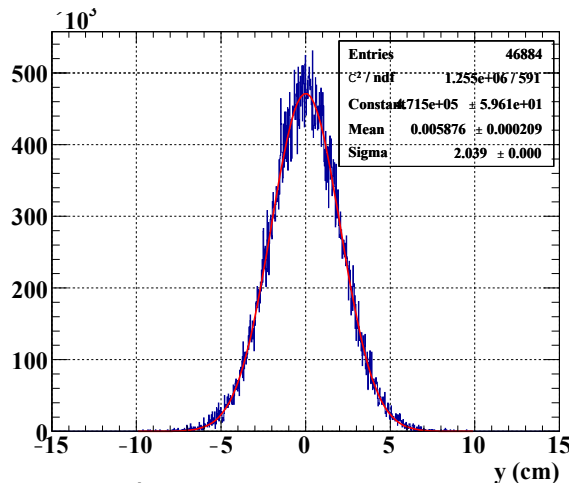
# BG properties

- RMD  $\gamma$  is identified from
  - RMD  $e^+$  energy
  - Time correlation b/w  $e^+$  &  $\gamma$

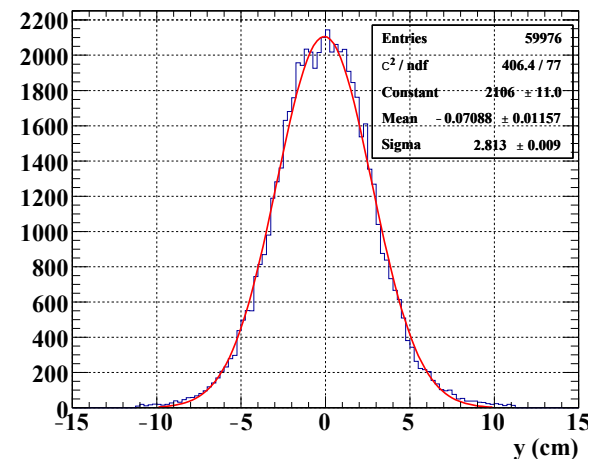


# Pileup

- Calculate pileup probability per readout region in which AI strips overlap

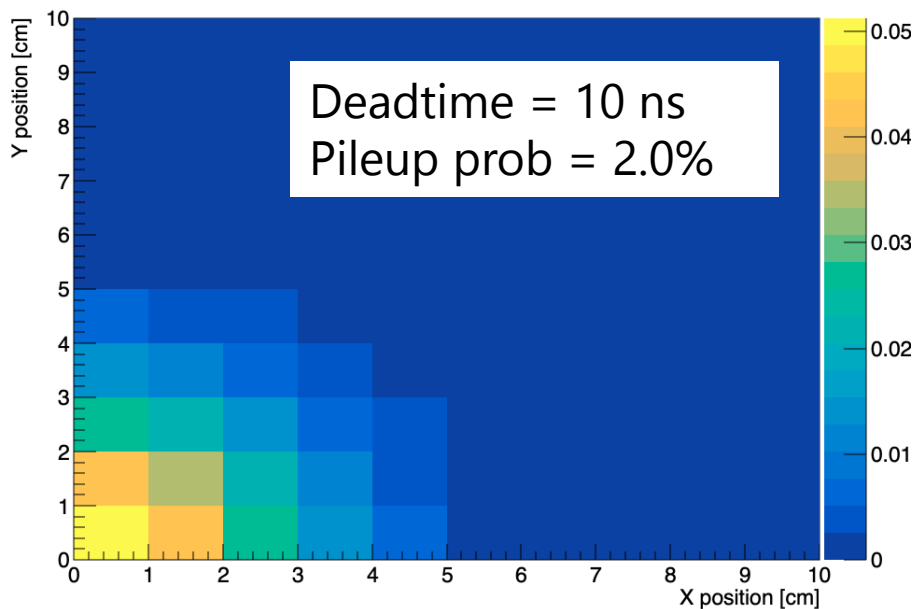


$\mu^+$  beam divergence  
 $\sigma = 2.0$  cm

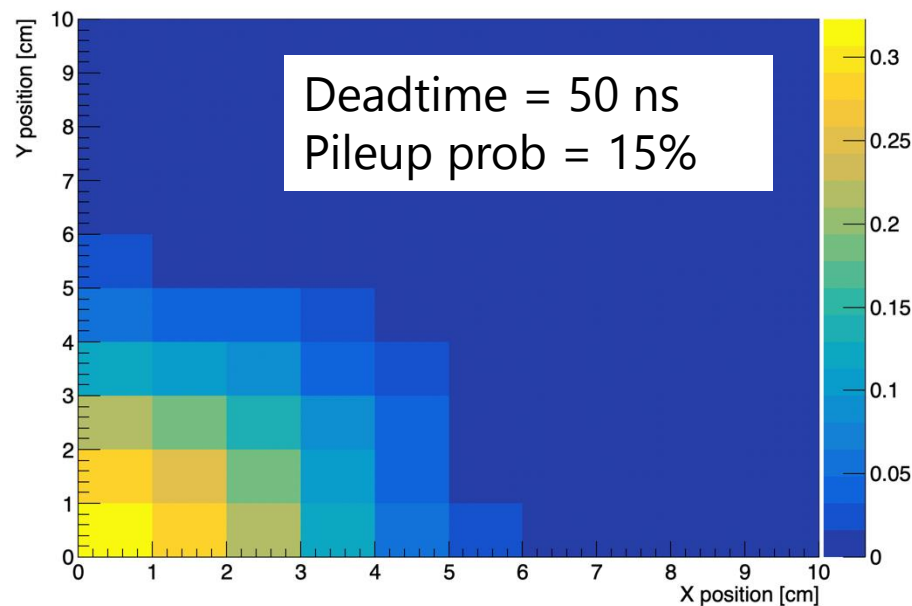


RMD  $e^+$  divergence  
 $\sigma = 2.8$  cm

Pileup probability



Pileup probability





# Pileup calculation

- $P_i$ : pileup probability per readout segmented region
- $\rho_i$ : probability to detect RMD  $e^+$  in the segmented region (= 2.8 cm)
- Total pileup probability is given by
- $\sum_{strips=256} P_i \rho_i$
- Probability of time difference  $t$  b/w continuous  $\mu^+$ :
- $p(t) = \frac{1}{\tau} \exp\left(-\frac{t}{\tau}\right)$ , where  $\frac{1}{\tau}$  is  $\mu^+$  rate in region  $i$
- Probability of pileup of  $\mu^+$  beam & RMD  $e^+$  in region  $i$ :
- $P_i = 1 - \exp\left(-\frac{t_{dead}}{\tau}\right)$ , where  $t_{dead}$  is deadtime when we cannot distinguish  $\mu^+$  & RMD  $e^+$

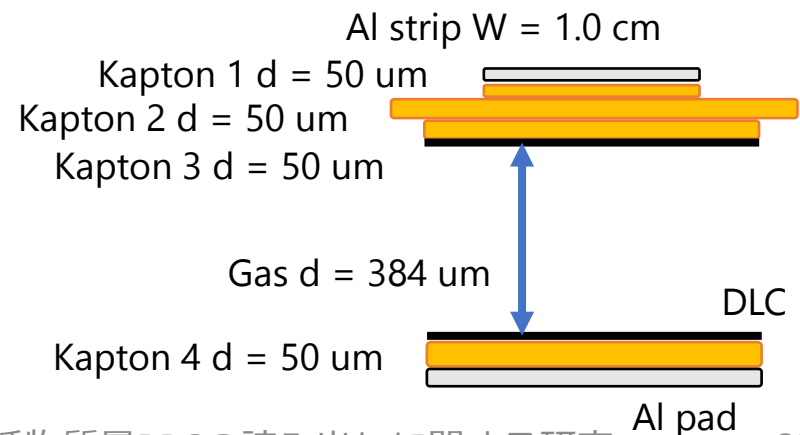
# Resistance per length

- Surface resistivity  $R_S = 1.1 \Omega/\text{sq}$
- $\rightarrow R = \frac{R_S}{W} = 110 \Omega/\text{m}$
- where  $W$  is width of Al strip, that is 1 cm

| Property            |                      | Units         | Aluminum Metallized Polyimide Film Typical Value |                         |
|---------------------|----------------------|---------------|--------------------------------------------------|-------------------------|
|                     |                      |               | LR-PI 100AM                                      | LR-PI 200AM             |
| Backing Thickness   |                      | $\mu\text{m}$ | 25                                               | 50                      |
| Aluminum Thickness  |                      | $\mu\text{m}$ | 0.2-0.5                                          | 0.2-0.5                 |
| Tensile Strength    |                      | MPa           | $\geq 140$                                       | $\geq 130$              |
| Elongation          |                      | %             | $\geq 45$                                        | $\geq 45$               |
| Shrinkage, at 150°C |                      | %             | 0.20                                             | 0.20                    |
| Surface Resistivity | The side of PI Film  | $\Omega$      | $\geq 1 \times 10^{12}$                          | $\geq 1 \times 10^{12}$ |
|                     | The side of Aluminum | $\Omega$      | $< 10^3$                                         | $< 10^3$                |

# Capacitance per length

- Think of geometry like this figure
- Ignore DLC plate because DLCs are sputtered on kaptons
- Kapton's relative permittivity  $\epsilon_r = 3.3$
- Give strip charge per length  $q$
- From Gauss's law, electric field is
- $q = \epsilon_0 \epsilon_r E W \rightarrow E = \frac{q}{\epsilon_0 \epsilon_r W}$



# Capacitance per length

- From the field, potential diff b/w Al strip and Cu pad is

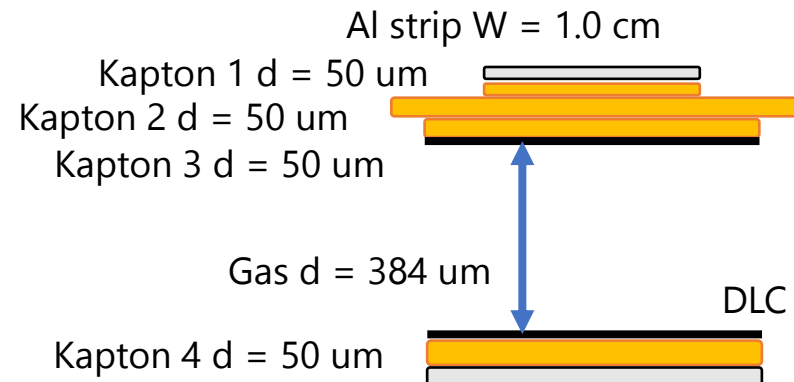
$$V = \int_0^d \frac{q}{\epsilon_0 \epsilon_r W} dx = \frac{qd}{\epsilon_0 \epsilon_r W}$$

- From  $V = \frac{q}{C'}$

- $C_i = \frac{\epsilon_0 \epsilon_r W}{d}$

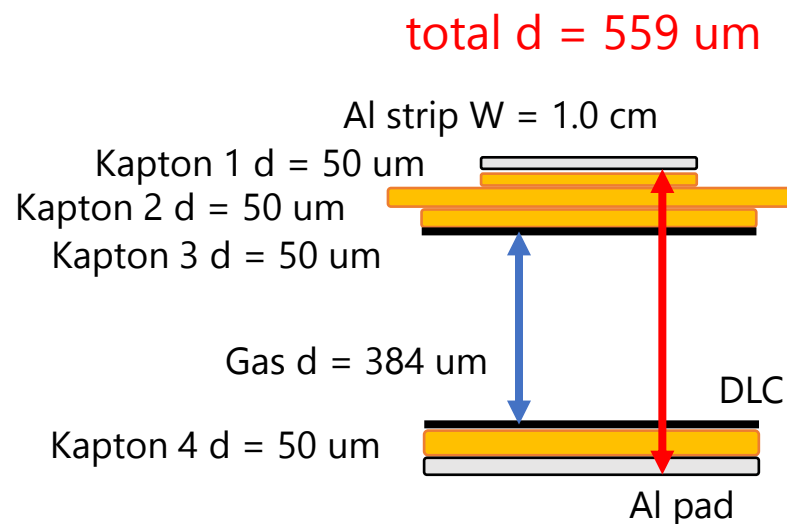
- From  $C_i = \frac{\epsilon_0 \epsilon_r W}{d}$ , where  $C_i$  is capacitance per length in layer  $i$

- Total capacitance  $C = 202 \text{ pF/m}$



# Inductance per length

- Think of geometry like this figure
- Assume current  $J$  flows only in Al strip (No current in Cu pad)
- From Ampere's law, magnetic field is
- $2W\mu B = J \rightarrow B = \frac{\mu J}{2W}$
- Permeability  $\mu = \mu_0$



# Inductance per length

- Magnetic flux  $\Phi$  is

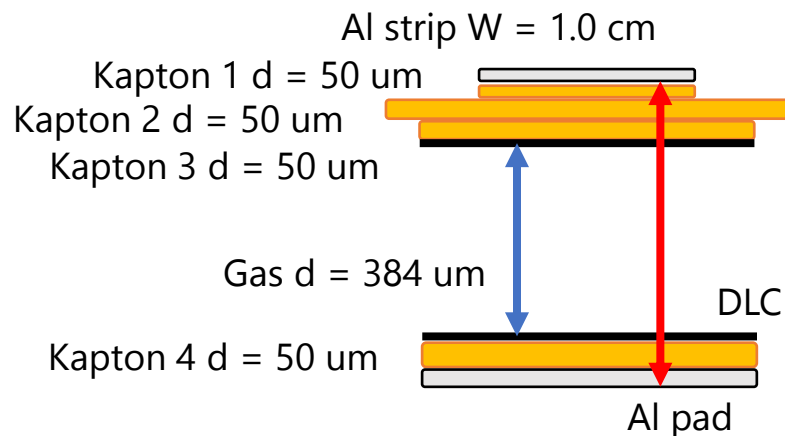
- $\Phi = \int \frac{\mu_0 J}{2W} dS = \frac{\mu_0 J}{2W} d$

- From  $\Phi$ , calculate  $V, L$

- $V = -\frac{d\Phi}{dt} = -\frac{\mu_0 d}{2W} \frac{dJ}{dt} = -L \frac{dJ}{dt} \rightarrow L = \frac{\mu_0 d}{2W} \text{ H/m}$

- $L = 35 \text{ nH/m}$

total d = 559  $\mu\text{m}$

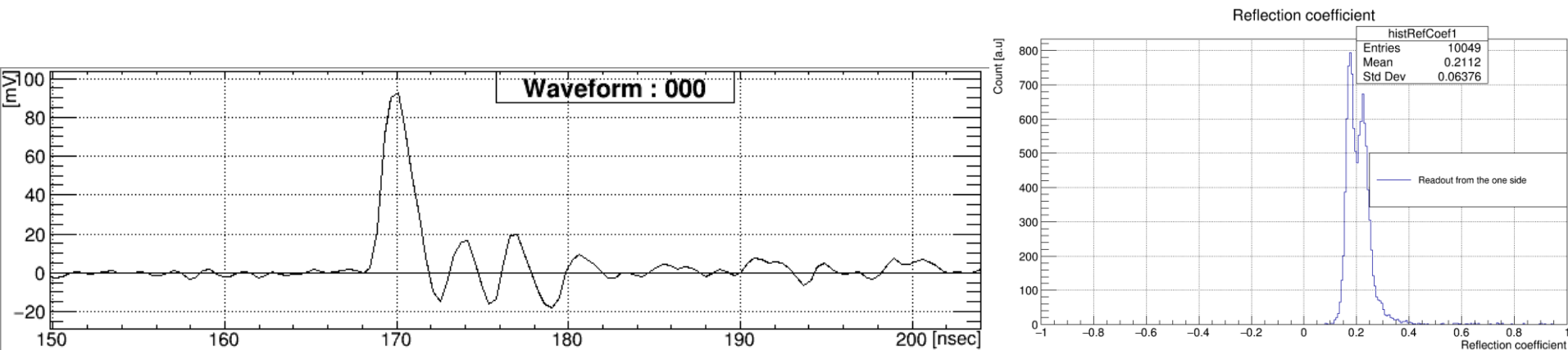


# Characteristic impedance

- Need to consider resistance  $R$  because we cannot ignore loss
- Characteristic impedance is
- $|Z_0| = \sqrt{\frac{R^2 + (\omega L)^2}{(\omega C)^2}}$
- where  $\omega$  is angular frequency
- Assume signals are triangle waves whose width is 4 ns
- In this case, assume  $\omega = 785 \text{ rad}/\mu\text{s}$
- $\rightarrow |Z_0| = \sqrt{\frac{R^2 + (\omega L)^2}{(\omega C)^2}} = 13.2 \Omega$

# Reflection

- Characteristic impedance of Al strip:  $Z_S = 13.2 \Omega$
- Characteristic impedance of LEMO cable:  $Z_0 = 50 \Omega$
- Reflection coefficient  $r = \frac{Z_0 - Z_S}{Z_0 + Z_S} = 0.58$
- In lab test,  $r \sim 0.21 \leftarrow$  Smaller than expectation



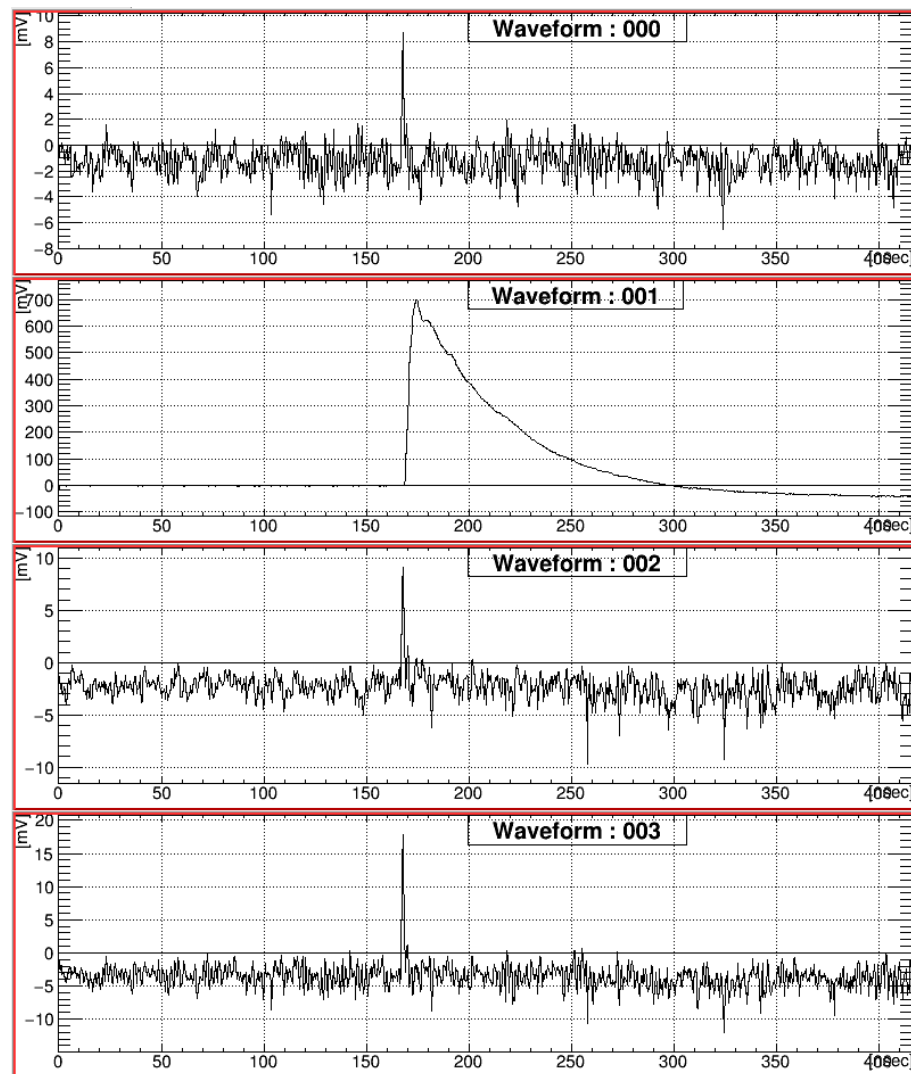


# Both readouts w/o resistors

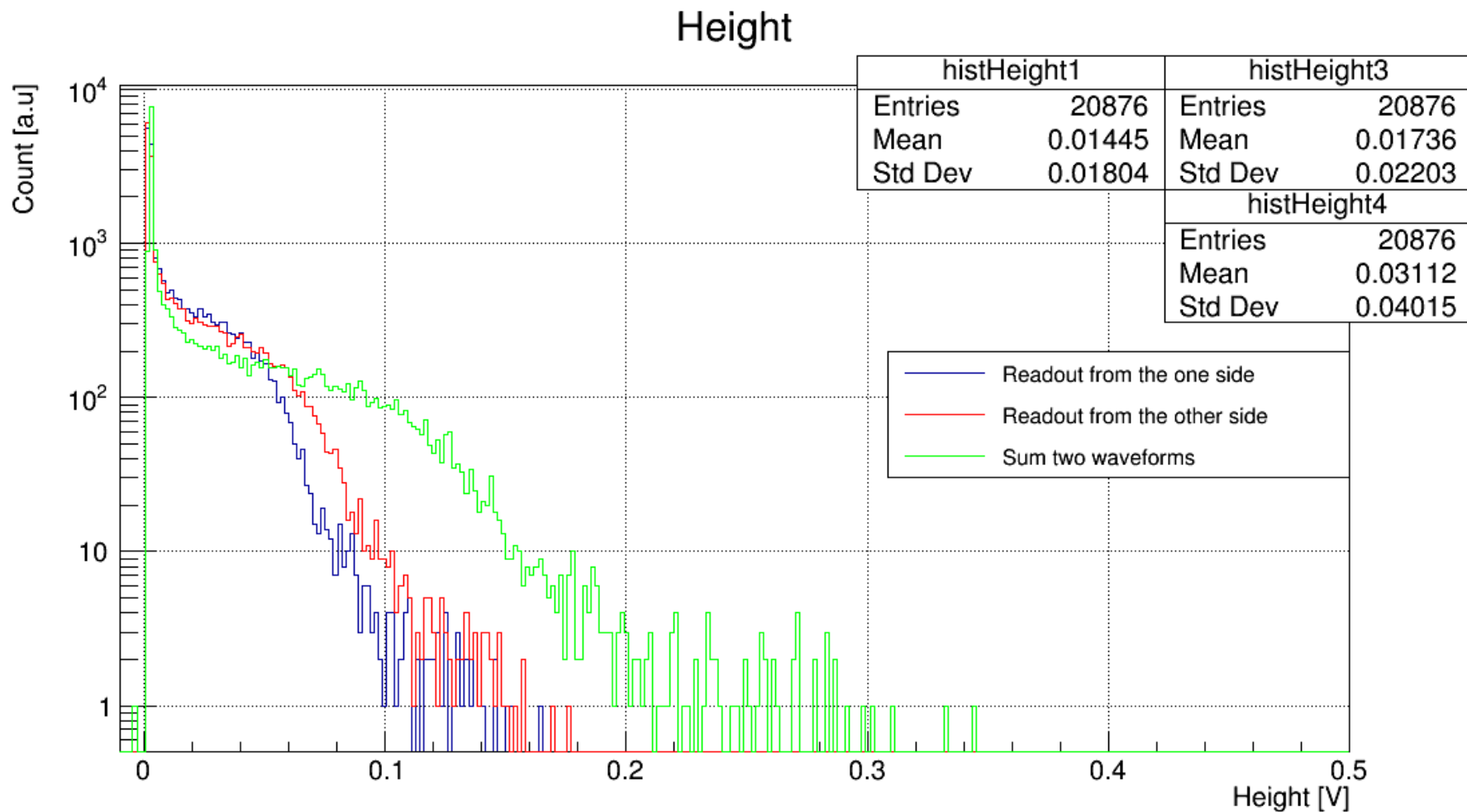
- Sum waveform up when readout from both sides of strip
- In some events, height is over threshold by summing up

→ Efficiency:

- Ch 0: 40.2%
- Ch 2: 42.5%
- Ch 3 (sum): 49.0%



# Both readouts w/o resistors



# Both readouts w/o resistors

Height

